

MOSFETs Silicon N-Channel MOS (π -MOSVII)

TK4P60DA

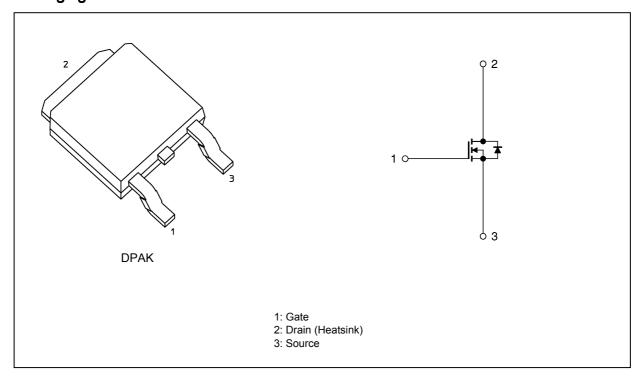
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 1.7 \Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (2) High forward transfer admittance: $|Y_{fs}| = 2.2 \text{ S (typ.)}$
- (3) Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 600 \text{ V)}$
- (4) Enhancement mode: V_{th} = 2.4 to 4.4 V (V_{DS} = 10 V, I_D = 1 mA)

3. Packaging and Internal Circuit





4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	600	V
Gate-source voltage			V _{GSS}	±30	
Drain current (DC)	(N	lote 1)	I _D	3.5	Α
Drain current (pulsed)	(1)	Note 1)	I _{DP}	14	
Power dissipation	(T _c = 25°C)		P_D	80	W
Single-pulse avalanche energy	(N	ote 2)	E _{AS}	132	mJ
Avalanche current	(N	ote 3)	I _{AR}	3.5	Α
Repetitive avalanche energy	(N	ote 3)	E _{AR}	8	mJ
Reverse drain current (DC)	(N	ote 1)	I _{DR}	3.5	Α
Reverse drain current (pulsed)	(N	lote 1)	I _{DRP}	14	
Channel temperature		·	T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	1.56	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 18.9 mH, R_{G} = 25 Ω , I_{AR} = 3.5 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



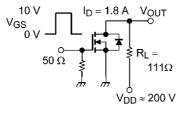
6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_		±1	μΑ
Drain cut-off current	I _{DSS}	V _{DS} = 600 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	600	_	_	V
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.4		4.4	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 1.8 A	_	1.7	2.2	Ω
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 1.8 A	0.6	2.2	_	S

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	490	_	pF
Reverse transfer capacitance	C _{rss}		_	3	_	
Output capacitance	C _{oss}		_	55	_	
Switching time (rise time)	t _r	See Figure 6.2.1	_	18	_	ns
Switching time (turn-on time)	t _{on}		_	40	_	
Switching time (fall time)	t _f		_	8	_	
Switching time (turn-off time)	t _{off}		_	55	_	



Duty \leq 1%, $t_W=$ 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A}$	_	11		nC
Gate-source charge	Q_{gs}		_	6		
Gate-drain charge	Q _{gd}		_	5	_	

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V_{DSF}	I_{DR} = 3.5 A, V_{GS} = 0 V	1	1	-1.7	V
Reverse recovery time	t_{rr} $I_{DR} = 3.5 \text{ A}, V_{GS} = 0 \text{ V}$		1000		ns	
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	5.0	_	μС



7. Marking

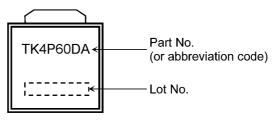


Fig. 7.1 Marking

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8. Characteristics Curves (Note)

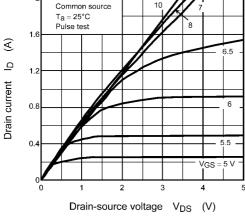


Fig. 8.1 I_D - V_{DS}

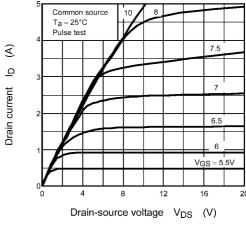


Fig. 8.2 I_D - V_{DS}

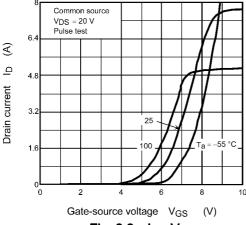


Fig. 8.3 $I_D - V_{GS}$

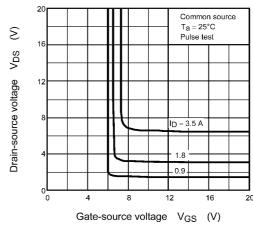


Fig. 8.4 V_{DS} - V_{GS}

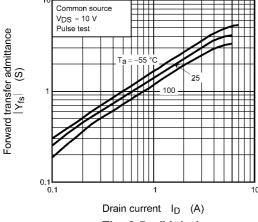


Fig. 8.5 |Yfs| - ID

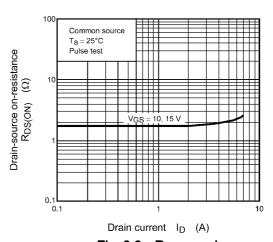


Fig. 8.6 R_{DS(ON)} - I_D

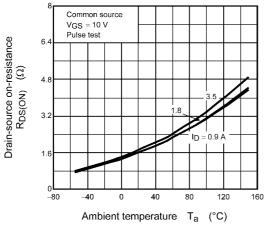


Fig. 8.7 R_{DS(ON)} - T_a

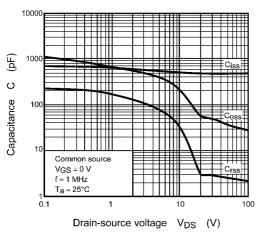


Fig. 8.9 Capacitance - V_{DS}

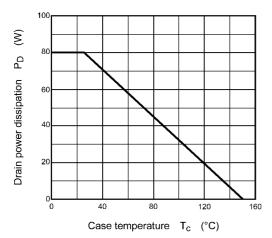


Fig. 8.11 P_D - T_c (Guaranteed Maximum)

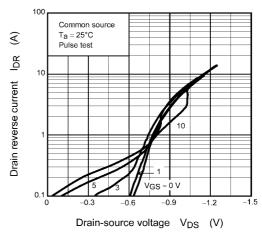


Fig. 8.8 IDR - VDS

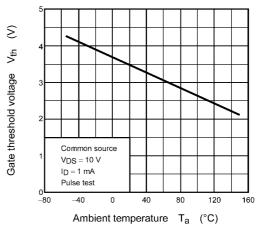


Fig. 8.10 V_{th} - T_a

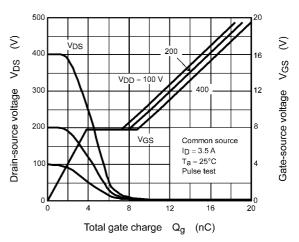


Fig. 8.12 Dynamic Input/Output Characteristics

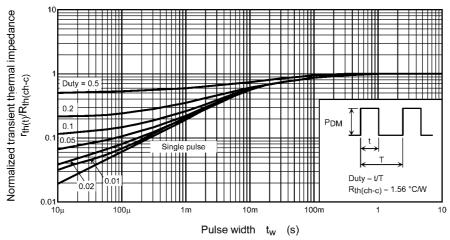


Fig. 8.13 $r_{th(t)}/R_{th(ch-c)} - t_w$ (Guaranteed Maximum)

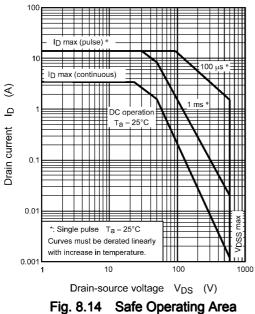


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

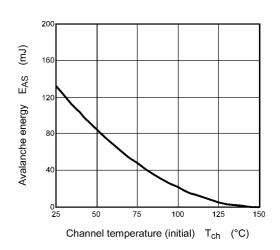


Fig. 8.15 E_{AS} - T_{ch} (Guaranteed Maximum)

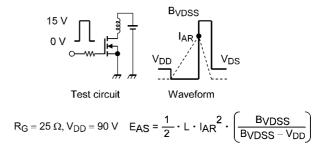


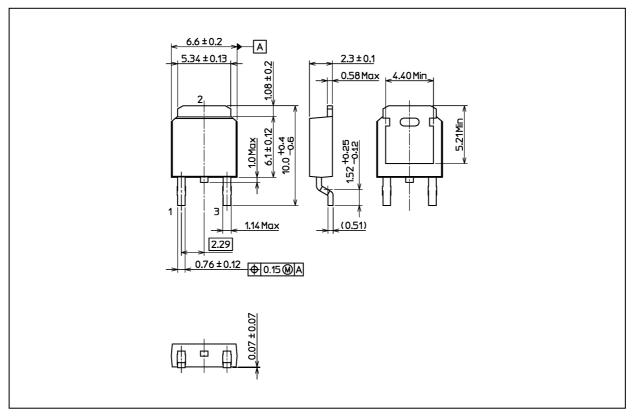
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



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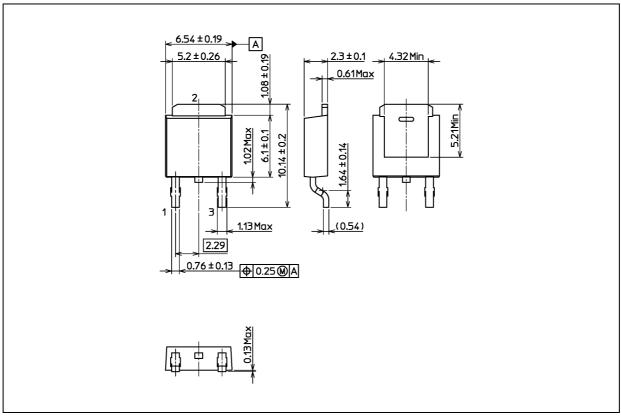
Weight: 0.36 g (typ.)

	Package Name(s)
JEDEC: TO-252	
TOSHIBA: 2-7K1S	
Nickname: DPAK	



Package Dimensions

Unit: mm



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Weight: 0.389 g (typ.)

Package Name(s)
JEDEC: TO-252
TOSHIBA: 2-7N1S
Nickname: DPAK

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